Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** 0.565 inches **Overall Height:** 0.565 inches **Overall Diameter:** 1.650 inches Internal Configuration: Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 900.0 breakover voltage, dc **Current Rating Per Characteristic:** 175.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 120.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug and 1 case Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0